L Number	Hits	Search Text	DB	Time stamp
-	1095	257/48	USPAT; US-PGPUB	2002/08/06 15:59
-	631	257/48 and (integrated adj circuit)	USPAT; US-PGPUB	2002/07/30 14:02
-	235	(257/48 and (integrated adj circuit)) and memory	USPAT; US-PGPUB	2002/07/30 14:02
-	46	((257/48 and (integrated adj circuit)) and memory) and electrode	USPAT; US-PGPUB	2002/07/30 14:03
-	1	("4517583").PN.	USPAT; US-PGPUB	2002/08/01 15:38
-	0	((integrated adj circuit) and (substrate near ((porous adj layer) and (HMMM))))	USPAT; US-PGPUB	2002/08/06 16:00
-	1	((integrated adj circuit) and (substrate same ((porous adj layer) and (HMMM))))	USPAT; US-PGPUB	2002/08/06 16:04
-	22	((integrated adj circuit) and (substrate same (porous adj layer) and (dielectric adj layer)))	USPAT; US-PGPUB	2002/08/06 16:34
-	32	((integrated adj circuit) and (substrate same (laminate adj layer)))	USPAT; US-PGPUB	2002/08/06 16:13
-	146	((integrated adj circuit) and (substrate same (porous adj layer)))	USPAT; US-PGPUB	2002/08/06 16:18
-	6	((integrated adj circuit) and (substrate same (porous adj layer) and ((capping or covering) adj layer)))	USPAT; US-PGPUB	2002/08/06 16:24
-	1	((integrated adj circuit) and (substrate same (porous adj layer) and (covering adj layer)))	USPAT; US-PGPUB	2002/08/06 16:29
-	0	((integrated adj circuit) and substrate and polyethermide and (polyvinylphenol or HMMM))	USPAT; US-PGPUB	2002/08/06 16:30
-	0	((integrated adj circuit) and substrate and polyethermide and HMMM)	USPAT; US-PGPUB	2002/08/06 16:31
-	0	((integrated adj circuit) and substrate and polyethermide and HMMM)	USPAT; US-PGPUB	2002/08/06 16:31
-	6	((integrated adj circuit) and substrate and HMMM)	USPAT; US-PGPUB	2002/08/06 16:32
-	57	((integrated adj circuit) and (porous adj layer) and (dielectric adj layer))	USPAT; US-PGPUB	2002/08/06 16:35
-	1	("4616339").PN.	USPAT; US-PGPUB	2004/01/21 17:01
-	1	("6133835").PN.	USPAT; US-PGPUB	2004/01/21 17:21
-	206005	integrated adj circuit	USPAT; US-PGPUB	2004/01/21 17:21
-	46991	(integrated adj circuit) and electrode	USPAT; US-PGPUB	2004/01/21 17:21
-	29777	((integrated adj circuit) and electrode) and transistor	USPAT; US-PGPUB	2004/01/21 17:21
-	12506	(((integrated adj circuit) and electrode) and transistor) and memory	USPAT; US-PGPUB	2004/01/21 17:25
-	1	6603154.pn.	USPAT; US-PGPUB	2004/01/21 17:25
-	1	"4931853".PN.	USPAT	2004/01/21 17:26
-	1	"5347146".PN.	USPAT	2004/01/21 17:26
-	1	"6201696".PN.	USPAT	2004/01/21 17:26
-	1	"6211527".PN.	USPAT	2004/01/21 17:28
-	1	"6239983".PN.	USPAT	2004/01/21 17:28
-	1	"6291880".PN.	USPAT	2004/01/21 17:28
-	1	"6310393".PN.	USPAT	2004/01/21 17:28
-	1	"6338783".PN.	USPAT	2004/01/21 17:29
-	1	"6396157".PN.	USPAT	2004/01/21 17:29

-	1	"6201696".PN.	USPAT	2004/01/21 17:29
-	1	"4814943".PN.	USPAT	2004/01/21 17:37
-	1	"5081562".PN.	USPAT	2004/01/21 17:37
-	1	"5386342".PN.	USPAT	2004/01/21 17:37
-	1	"5398160".PN.	USPAT	2004/01/21 17:37
-	1	"5940271".PN.	USPAT	2004/01/21 17:37
-	1	"20010045593"	USPAT; US-PGPUB	2004/01/22 15:38
-	922	257/679	USPAT; US-PGPUB	2004/01/22 15:39
-	448	257/679 and memory	USPAT; US-PGPUB	2004/01/22 15:39
-	80	(257/679 and memory) and electrode	USPAT; US-PGPUB	2004/01/22 15:52
-	698	pentacene	USPAT; US-PGPUB	2004/01/22 15:52
-	108	pentacene and memory	USPAT; US-PGPUB	2004/01/22 15:53
-	3	(pentacene and memory) and pentacene near electrode	USPAT; US-PGPUB	2004/01/22 15:55
-	4353	polyaniline	USPAT; US-PGPUB	2004/01/22 15:56
-	626	polyaniline and memory	USPAT; US-PGPUB	2004/01/22 15:56
-	2	"626" and polyaniline near electrode	USPAT; US-PGPUB	2004/01/22 15:57
-	0	"626" and polyaniline near memory	USPAT; US-PGPUB	2004/01/22 15:58
-	0	"626" and polyaniline same memory	USPAT; US-PGPUB	2004/01/22 16:26
-	7374	mems	USPAT; US-PGPUB	2004/01/22 16:27
-	63	mems and driving adj circuit	USPAT; US-PGPUB	2004/01/22 16:27
-	922	257/679	USPAT; US-PGPUB	2004/01/23 12:45
-	448	257/679 and memory	USPAT; US-PGPUB	2004/01/23 12:45
-	38	(257/679 and memory) and bridge	USPAT; US-PGPUB	2004/01/23 12:45
-	1	"5313052".PN.	USPAT	2004/01/23 13:06
-	1	"5321240".PN.	USPAT	2004/01/23 13:06
-	1	"5337063".PN.	USPAT	2004/01/23 13:07
-	1	"6073856".PN.	USPAT	2004/01/23 13:07
-	1	"6184846".PN.	USPAT	2004/01/23 13:08
-	1	"6255725".PN.	USPAT	2004/01/23 13:08
-	58	(257/679 and memory) and transistor	USPAT; US-PGPUB	2004/01/23 13:34
-	28	(("5061650") or ("5138412") or ("5192702") or ("5206183") or ("5284787") or ("5364817") or ("5451537") or ("5459094") or ("5459344") or ("5543345") or ("5604147") or ("5754390") or ("5792689") or ("5795805") or ("5817555") or ("5937294") or ("6018172") or ("6027970") or ("6124607") or ("6140201") or ("6150691") or ("6177310") or ("6207523") or ("6218237") or ("6218288") or ("6235639") or ("6258691") or ("6281072")).PN.	USPAT; US-PGPUB	2004/01/27 11:45